



#### 30V N-Channel Enhancement Mode MOSFET

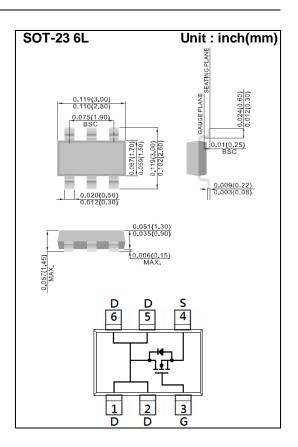
Voltage 30 V Current 6.4A

#### **Features**

- RDS(ON), VGS@10V, ID@6.4A<37m $\Omega$
- RDS(ON) , VGS@4.5V, ID@4.5A<43mΩ</li>
- RDS(ON) , VGS@2.5V, ID@2.9A<59mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S00



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 12	V
Continuous Drain Current		I <sub>D</sub>	6.4	Α
Pulsed Drain Current		I <sub>DM</sub>	25.6	Α
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	62.5	°C/W





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}$ =0V, $I_D$ =250uA	30	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	0.5	0.85	1.3	V		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =6.4A	-	29	37	mΩ		
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.5A	-	32	43			
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =2.9A	-	42	59			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V	-	0.01	1	uA		
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA		
Dynamic								
Total Gate Charge	$Q_g$	V <sub>DS</sub> =15V, I <sub>D</sub> =6.4A, V <sub>GS</sub> =10V (Note 1,2)	-	6	-	nC		
Gate-Source Charge	$Q_{gs}$		-	1.3	-			
Gate-Drain Charge	$Q_{gd}$		-	1.7	-			
Input Capacitance	Ciss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V,	-	490	-	pF		
Output Capacitance	Coss		-	44	-			
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	32	-			
Switching								
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =15V, $I_{D}$ =6.4A, $V_{GS}$ =10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	3.2	-	ns		
Turn-On Rise Time	tr		-	63	-			
Turn-Off Delay Time	td <sub>(off)</sub>		-	79	-			
Turn-Off Fall Time	tf		-	81	-			
Drain-Source Diode								
Maximum Continuous Drain-Source					2.0	А		
Diode Forward Current	I <sub>S</sub>		-	-	2.0			
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.74	1.2	V		

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

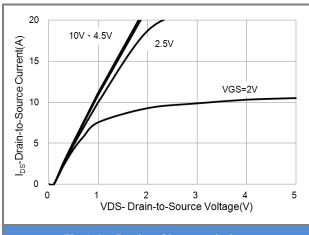
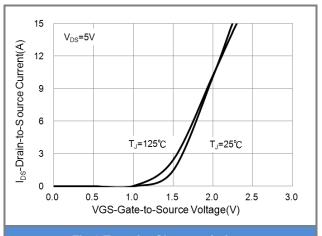


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

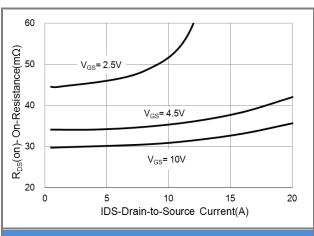


Fig.3 On-Resistance vs. Drain Current

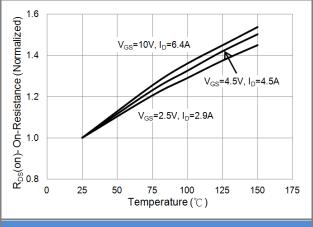
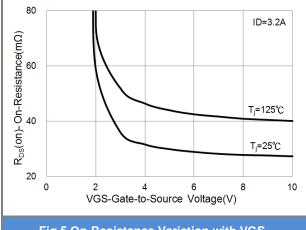


Fig.4 On-Resistance vs. Junction temperature





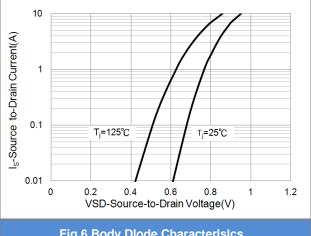


Fig.6 Body Dlode CharacterIsIcs





#### **TYPICAL CHARACTERISTIC CURVES**

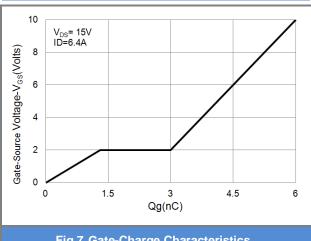


Fig.7 Gate-Charge Characteristics

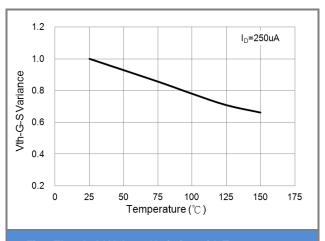


Fig.8 Threshold Voltage Variation with Temperature.

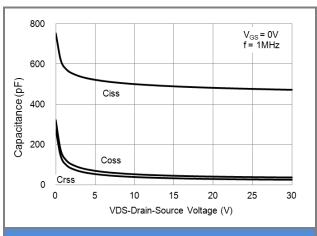


Fig.9 Capacitance vs. Drain-Source Voltage.

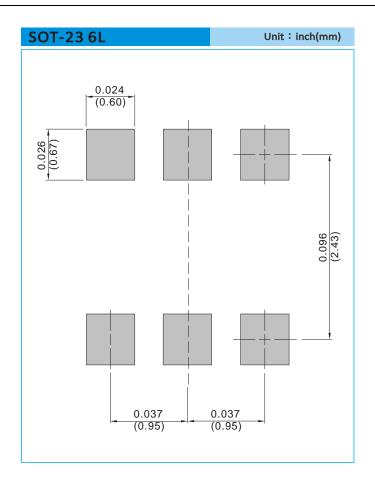




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJS6400_S1_00001	SOT-23 6L	3K pcs / 7" reel	S00	Halogen free
PJS6400_S2_00001	SOT-23 6L	10K pcs / 13" reel	S00	Halogen free

#### **MOUNTING PAD LAYOUT**







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